## **Biasing Guidelines**

- Basic guidelines for biasing a common-emitter BJT amplifier that is stable over temperature, voltage and part variations.
  - 1. Choose an appropriate transistor for your circuit. Make sure that  $\beta \ge 100$  at the anticipated current level. Allows the assumption that  $lc \approx le$  and  $lb \approx 0$ .
  - Choose *I<sub>e</sub>* to set the transistor transconductance. Lessens the dependence of *I<sub>c</sub>* on Beta and temperature.
  - 3. Choose a collector resistor to set  $V_c \approx 0.5 V_{cc}$ . Gives the greatest output voltage swing.
  - 4. With chosen  $I_e$ , pick  $R_e$  such that  $V_e \ge 10 V_t$ . Voltages from 0.5V 1V are typical.

Minimizes variations in  $I_c$  due to  $V_{be}$  temperature dependence.

5. Create the base bias resistor network so that  $V_b = V_e + 0.6$  with the constraint that the current through the bias resistors is 0.1/e. With  $\beta \ge 100$ , this corresponds to a bias resistor current that is  $\ge 10I_b$ . Keeps variations in  $\beta$  (thus,  $I_b$ ) from effecting  $V_b$ .